FEATURES

- Ultrafast recovery time
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- · Guaranteed avalanche
- · Specified at operating conditions
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION / APPLICATIONS

These diodes are optimized to reduce losses and EMI / RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for freewheeling, flyback, power converters, motor drives, and other applications where high speed and reduced switching losses are design requirements.

ABSOLUTE MAXIMUM RATINGS PARAMETER SYMBOL **TEST CONDITIONS** VALUES UNITS V 600 Cathode to anode voltage V_{RRM} $T_C = 100 \degree C$ Maximum continuous forward current 8 I_{F} Single pulse forward current 60 А I_{FSM} 24 Peak repetitive forward current I_{FRM} $T_C = 100 \ ^{\circ}C$ 14 W Maximum power dissipation P_D Operating junction and storage temperature range T_J, T_{Sta} -55 to +150 °C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-				
Forward voltage	V _F	I _F = 8 A		-	1.4	1.7	V		
		I _F = 16 A	See fig. 1	-	1.7	2.1			
		I _F = 8 A, T _J = 125 °C		-	1.4	1.7			
Maximum reverse	I _R	$V_{R} = V_{R}$ rated	-	0.3	5.0	μA			
leakage current		$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	-	100	500				
Junction capacitance	C _T	V _R = 200 V See fig. 3		-	10	25	pF		
Series inductance	L _S	Measured lead to lead 5 mm from pa	ckage body	-	8.0	-	nH		

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HEXFRED[®] Ultrafast Soft Recovery Diode, 8 A

Q 2, 4

Single die

പ 1

N/C

ტ 3

Anode

PRODUCT SUMMARY										
Package	TO-252AA (D-PAK)									
I _{F(AV)}	8 A									
V _R	600 V									
V _F at I _F	1.4 V									
t _{rr} typ.	18 ns									
T _J max.	150 °C									



Diode variation





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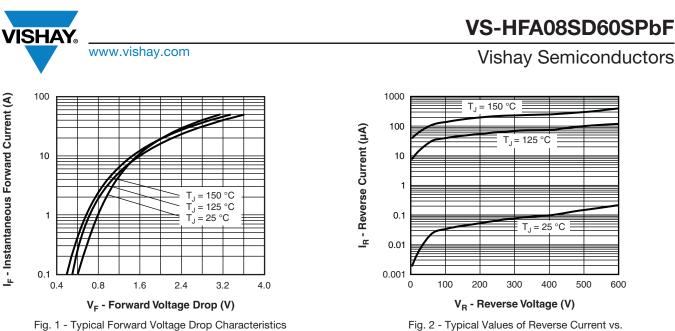


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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	-	18	-				
		T _J = 25 °C		-	37	55	ns		
		T _J = 125 °C	I _F = 8 A dI _F /dt = 200 A/μs V _R = 200 V	-	55	90			
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3.5	5.0	A nC		
		T _J = 125 °C		-	4.5	8.0			
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	65	138			
		T _J = 125 °C		-	124	360			
Rate of fall of recovery current	dl _{(rec)M} /dt	T _J = 25 °C]	-	240	-	A/µs		
		T _J = 125 °C		-	210	-	Ανμs		

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	MIN.	TYP.	MAX.	UNITS					
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	150	°C			
Thermal resistance, junction to case	R _{thJC}		-	-	3.5	°C/W			
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	0/10			
Weight			-	2.0	-	g			
Weight			-	0.07	-	oz.			
Marking device		Case style D-PAK	HFA08SD60S						



Reverse Voltage

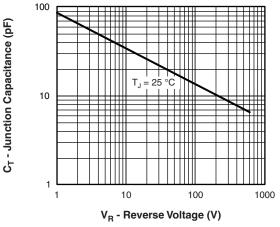


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

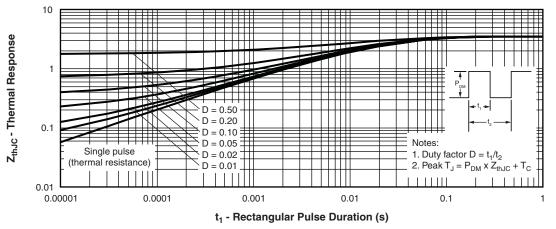


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



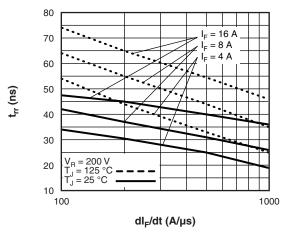


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

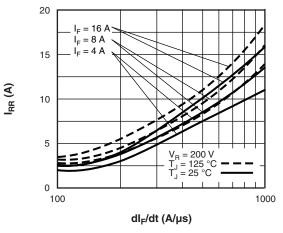
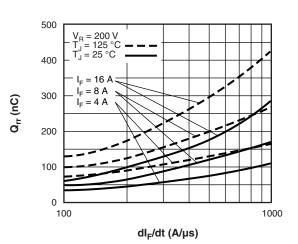


Fig. 6 - Typical Recovery Current vs. dl_F/dt

VS-HFA08SD60SPbF

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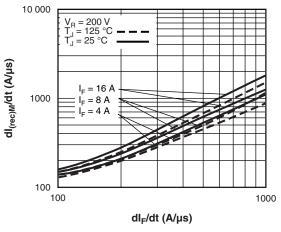


Fig. 8 - Typical dl_{(rec)M}/dt vs. dl_F/dt

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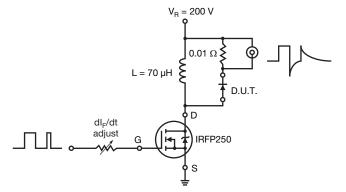
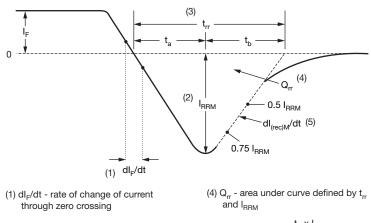


Fig. 9 - Reverse Recovery Parameter Test Circuit



(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.



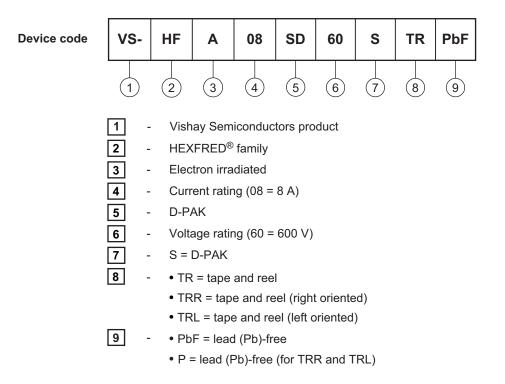
- (5) dI_{(rec)M}/dt peak rate of change of current during t_b portion of t_{rr}
- Fig. 10 Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE



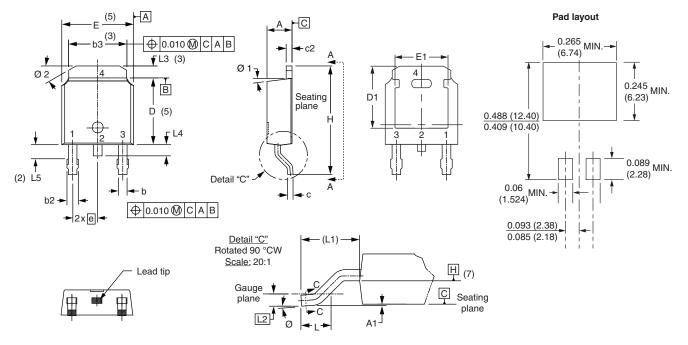
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						





D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL -	MILLIMETERS		INCHES		NOTES		SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NUTES		STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094		e		2.29 BSC		0.090 BSC		
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51 BSC		0.020 BSC		
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

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